

Charge stability and charge-state-based spin readout of shallow nitrogen-vacancy centers in diamond

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Spin-based applications of the negatively charged nitrogen-vacancy (NV) center in diamonds require efficient spin readout. One approach is the spin-to-charge conversion (SCC), relying on mapping the spin states onto the neutral (NV⁰) and negative (NV⁻) charge states followed by a subsequent charge readout. With high charge-state stability, SCC enables extended measurement times, increasing precision and minimizing noise in the readout compared to the commonly used fluorescence detection. Nano-scale sensing applications, however, require shallow NV centers within a few nm distance from the surface where surface related effects might degrade the NV charge state. In this article, we investigate the charge state initialization and stability of single NV centers implanted ≈ 5 nm below the surface of a flat diamond plate. We demonstrate the SCC protocol on four shallow NV centers suitable for nano-scale sensing, obtaining a reduced readout noise of 5–6 times the spin-projection noise limit. We investigate the general applicability of SCC for shallow NV centers and observe a correlation between NV charge-state stability and readout noise. Coating the diamond with glycerol improves both charge initialization and stability. Our results reveal the influence of the surface-related charge environment on the NV charge properties and pave the way towards efficient spin-state readout of shallow NV centers suitable for nano-scale sensing.

INTRODUCTION

The negatively charged nitrogen-vacancy (NV⁻) center in diamond has excellent spin properties at room temperature with a long lifetime and coherence, enabling a broad range of applications. These include the sensing of magnetic and electric fields with high sensitivity and nanometer-scale spatial resolution [1–3]. Central to any NV⁻ center sensing task is the ability to initialize and read out the spin state optically. The most common approach to read out the spin state is via the fluorescence strength, enabled by spin-dependent intersystem crossing from the triplet excited to a singlet state [4]. The intersystem crossing mechanism sets a lower limit on the spin readout duration to around 300 ns as determined by the singlet-state lifetime [5] that, together with low photon counts in the order of 0.1 per readout hinders the efficient measurement of the spin state. In the context of sensing, it is thus required to repeat the scheme multiple times in order to build up sufficient photon statistics to determine the spin state [5, 6]. Nanopillars [7] or solid immersion lenses [8] might be used to increase the photon collection efficiency and improve the readout signal-to-noise ratio (SNR), but yet the attainable photon count rates are not sufficient to measure the spin state in a single shot.

Another approach for spin readout involves the charge degree of freedom of the NV center, that in addition to NV⁻ may also exist in the neutral charge state NV⁰. Deep in the bulk, the charge state ratio between the two

is highly stable in the dark or under weak optical excitation [9–11]. With zero-phonon lines at 575 nm and 637 nm for NV⁰ and NV⁻, respectively, and therefore different absorption spectra, the charge states are distinguishable via selective illumination that excites NV⁻ but not NV⁰ [12]. In the spin-to-charge conversion (SCC) protocol [13], population of the $m_s = 0$ spin state is transferred to NV⁰ via a photoionization process [12, 14], while the population of the $m_s = \pm 1$ spin state remains in the NV⁻ charge state. The subsequent charge-state readout may be long and efficient provided sufficient photon counts and charge-state stability is attained within the readout duration. Using this approach, > 1 photon per readout may be detected when the system is in $m_s = \pm 1$, significantly increasing SNR per readout as compared to standard fluorescence detection.

Applying the SCC protocol to an NV center in a diamond nanobeam with significantly improved photon collection efficiency compared to bulk diamond, Shields et al. [13] demonstrated an SNR ≈ 0.55 per readout corresponding to a noise factor of $\approx 3\sigma_p$, where σ_p is the spin-projection noise limit [15]. More recently, the SCC readout has been demonstrated for NV center ensembles in nano- [16] and bulk diamonds [17], and for single NV centers deep in the bulk [18]. Nano-scale sensing tasks including nuclear magnetic resonance (NMR) [19, 20] or sensing of free radicals [21] however require single NV centers within a few nm from the diamond surface where the sensing signal is sufficiently strong [22]. In the vicinity of the surface, effects including upward energy band

bending [23] and electron tunneling to nearby surface traps [10] are known to cause ionization of NV^- to NV^0 at rates in the order of the inverse readout time or even faster. Although it has been demonstrated that SCC can work for NV centers implanted within a few nm from the surface in diamond nano-pillars [24], the general applicability of the SCC protocol to near-surface NV centers as well as the possible detrimental impact of surface-related effects remains unexplored as of yet.

In this article, we explore the charge-state stability and the SCC protocol on single NV centers implanted ≈ 5 nm below the surface of a flat diamond plate. The implanted side of the diamond is accessible to apply a solution bath or nano-objects, an experimental configuration relevant for nano-scale sensing and spin mechanical coupling. We use a simplified experimental approach with only two lasers, one at 532 nm for NV charge and spin initialization and another at 594 nm for spin-state selective ionization and charge-state readout. From the detailed characterization of 33 single NV centers, we observe a strong variability of the probability to initialize into NV^- . We present data of four NV centres labelled $NV_A - NV_D$ that are representative of the distribution. We show that after coating the diamond with deuterated glycerol, the initialization probability into NV^- increases while simultaneously the ionization rate from NV^- to NV^0 decreases as compared to the pristine surface. Furthermore, we demonstrate the general applicability of the SCC protocol on four near-surface NV centers. Our investigations indicate the importance of the local charge environment for the NV charge-state stability as well as the overall performance of the SCC protocol. We obtain a noise level as low as $\approx 5\sigma_p$ corresponding to a single-shot SNR ≈ 0.3 , a result comparable to that obtained with NV centers in the bulk or nano-structures with higher attainable photon count rates.

EXPERIMENTAL METHODS

All measurements reported in this article were conducted on a 50- μm -thin electronic-grade diamond plate (Element Six) with (100) surface orientation. The sample was overgrown with a 100-nm-thick and ^{12}C -enriched ($< 0.05\%$ ^{13}C) layer of diamond using chemical vapor deposition. NV centers were created via implantation of $^{15}\text{N}^+$ ions with an energy of 2.5 keV, and a dose of $5 \times 10^8 \text{cm}^{-2}$ (process pressure $< 1 \times 10^{-7} \text{mbar}$) [25]. Subsequent annealing in ultra-high vacuum at 1000 $^\circ\text{C}$ for 3 hours heals radiation damage due to the ion bombardment, mobilizes vacancies, and through capture of an implanted nitrogen, yields a Gaussian-like distribution of single NV centers with a mean depth ≈ 5 nm below the surface. The diamond was cleaned in a boiling acid mixture consisting in equal parts of nitric, perchloric, and sulfuric acid (tri-acid cleaning) to remove surface contaminants [26] and

creating a hydrophilic surface with partial oxygen termination [27, 28]. With these near-surface NV centers and using a Hahn-echo sequence, we measured T_2 coherence times in the range from 3 to 15 μs , in good agreement with values obtained for a different sample fabricated using the same equipment and process parameters [29].

We used a home-built scanning confocal microscope setup with an NA=1.4 immersion-oil objective to inves-

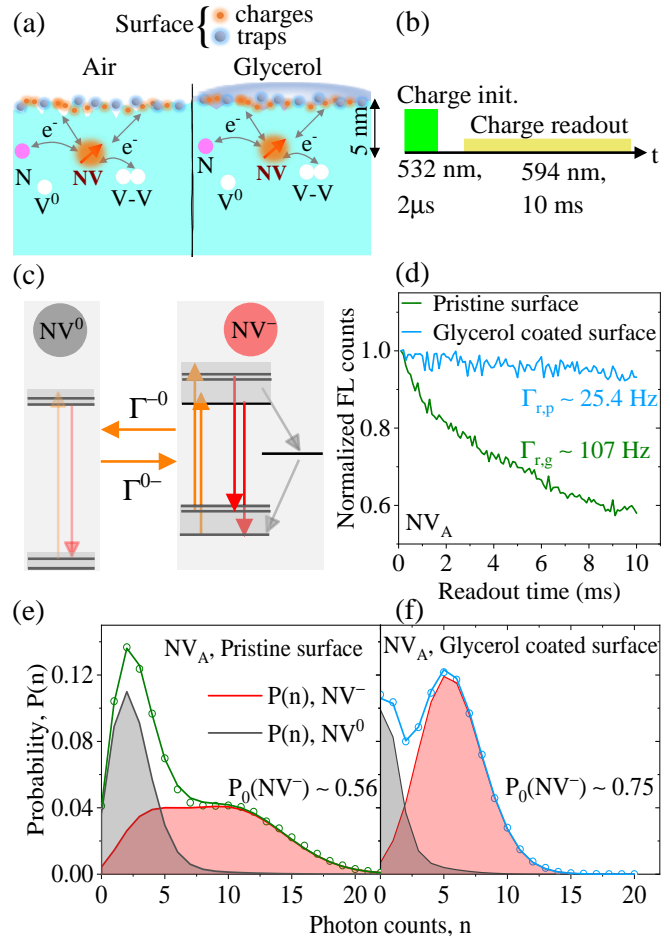


FIG. 1. Surface-related effects and charge-state stability of shallow NV centers. (a) Illustration of ≈ 5 nm shallow NV centers and their interaction with the local charge environment with glycerol passivating surface charges and traps. (b) Pulse sequence to measure the NV^- charge-initialization probability $P_0(NV^-)$, applying 532 nm initialization and 594 nm readout pulses, respectively. (c) Illustration of the energy levels of NV^0 and NV^- together with allowed transition rates. The 594 nm laser ideally only excites NV^- . For strong excitation, it can ionize (Γ^0) NV^- to NV^0 and induce recombination (Γ^0-) from NV^0 to NV^- . The charge-state switching is suppressed for weak excitation, and the NV^0 center remains dark under 594 nm excitation. (d) Fluorescence evolution during the readout pulse, where the charge stability improves with glycerol. (e, f) Photon-number distribution $P(n)$ of NV_A with the pristine (e) and the glycerol-coated (f) surface. The gray- and red-shaded areas illustrate the respective contributions of NV^0 and NV^- .

tigate the NV charge state and implement the SCC protocol. The radiation amplitude of each laser, 532 nm and 594 nm, was controlled using acousto-optic modulators in a double-pass configuration to generate pulses for charge and spin initialization, shelving, ionization and readout. After long-pass filtering with a cut-on at 650 nm, the NV fluorescence signal was detected with a single-photon-sensitive avalanche photodiode with dark counts < 200 Hz. Together with the selective excitation at 594 nm, this configuration ensures, to a very high degree, that the signal stems from the NV^- emission. With a motorized 3-axis translation stage we controlled the position of a permanent magnet to produce a bias magnetic field of ≈ 7 mT along one of the four [111] crystal axes that all NV centers investigated here are aligned along. The diamond plate was horizontally mounted on a 170- μ m-thick cover glass with the NV layer on the top side, exposed either to air or solution and suitable for nanoscale sensing [Fig. 1(a)]. The excitation lasers pass from below through the cover glass and the diamond, and the fluorescence is collected from the same side [30].

RESULTS

Charge-state initialization and stability

We begin our investigations with characterizing the charge state of 33 near-surface NV centers by applying the protocol illustrated in Fig. 1(b). The 2 μ s short 532 nm pulse (continuous-wave power ≈ 400 μ W) has the purpose to initialize the NV center into NV^- , followed by a weak 10 ms long 594 nm pulse (continuous-wave power ≈ 3.5 μ W) to selectively read out the charge state. The 594 nm readout laser mainly excites NV^- as illustrated on the energy level diagrams in Fig. 1(c), which leads to a charge state depend fluorescence intensity. During the readout the NV center can ionize from NV^- to NV^0 and recombine from NV^0 to NV^- with the rates Γ^{-0} and Γ^{0-} respectively. The charge-state switching rates increase with increasing optical excitation power. The stability of the normalized fluorescence intensity during a readout pulse for NV_A is shown in Fig. 1(d). The photon-number distribution $P(n)$ obtained from NV_A with the pristine diamond surface is plotted in Fig. 1(e), where the gray and red-shaded areas illustrate the contributions of NV^0 and NV^- , respectively. We fitted the temporal evolution of $P(n)$ with a model [13] (100 μ s resolution) to extract the photon detection rates γ^0 and γ^- from NV^0 and NV^- , respectively, the NV^- to NV^0 ionization rate Γ^{-0} , the NV^0 to NV^- recombination rate Γ^{0-} , and the NV^- population $P_0(NV^-)$ at the start of the readout pulse. With the pristine diamond surface, we obtain $P_0(NV^-) = 0.55$ and $\Gamma^{-0} = 103$ Hz, while $\Gamma^{0-} = 8.5$ Hz. Afterwards, we coated the diamond surface with glycerol, resulting in a significant change of $P(n)$ as presented in

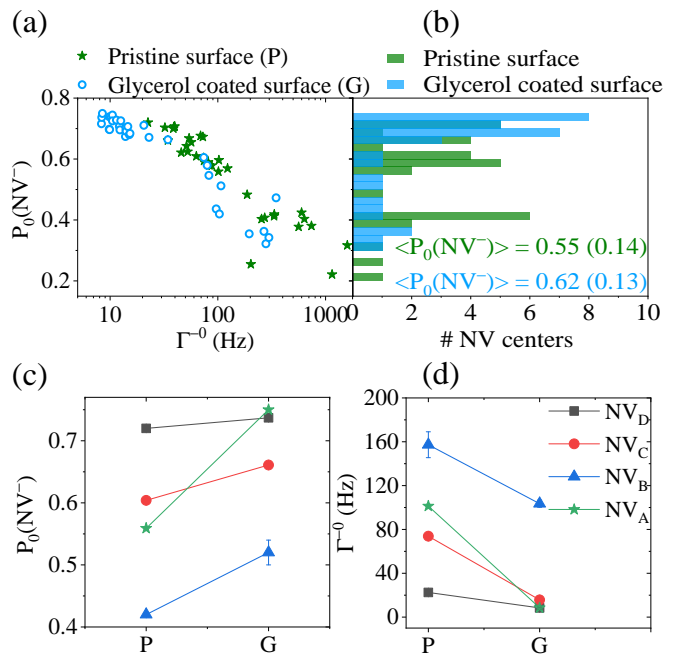


FIG. 2. (a) NV^- charge initialization probability $P_0(NV^-)$ versus ionization rate Γ^{-0} for 33 NV centers with the pristine and the glycerol-coated surfaces. (b) Histogram of $P_0(NV^-)$. (c, d) Comparison of $P_0(NV^-)$ and Γ^{-0} for pristine (P) and glycerol-coated (G) surface for emitters NV_A – NV_D .

Fig. 1(f). The value of $P_0(NV^-)$ substantially increases to 0.75 and is now comparable to results from NV centers deeper in the bulk [12, 31]. Furthermore, Γ^{-0} substantially decreases to 8 Hz, demonstrating improved charge-state stability during readout after coating the diamond surface with glycerol.

The increased charge-state stability of NV_A after application of glycerol is also directly seen in the average fluorescence during the readout pulse as shown in Fig. 1(d). With the pristine surface, the fluorescence level reduces with a rate $\Gamma_{r,p} \approx \Gamma^{-0} + \Gamma^{0-} \approx 107$ Hz, while after application of glycerol the reduction is lower with a rate $\Gamma_{r,g} \approx 25.4$ Hz.

In Fig. 2(a), we plot the NV^- initialization probability $P_0(NV^-)$ versus the ionization rate Γ^{-0} for 33 single NV centers both with the pristine diamond surface and after the application of glycerol. The histogram for $P_0(NV^-)$ is shown in Fig. 2(b). We observe an anti-correlation between $P_0(NV^-)$ and Γ^{-0} irrespective of the surface condition. Upon the application of glycerol, $P_0(NV^-)$ increases for all NV centers (see Fig. 2(c) for NV_A – NV_D) and correspondingly Γ^{-0} reduces (see Fig. 2(d) for NV_A – NV_D).

Our results show that the application of glycerol generally increases the charge-initialization probability of the ≈ 5 nm shallow NV centers into the NV^- state with a maximum probability $\approx 75\%$ comparable to that of NV centers in the bulk. However, for some NV centers includ-

ing NV_B , the charge-initialization probability (ionization rate) remains low (high) and only marginally improves compared to the pristine surface.

SCC protocol

In the next step, we implement the SCC protocol [Fig. 3(a)] on four NV centers (NV_A – NV_D) that have different $P_0(NV^-)$ and we benchmark the performance of SCC by estimating the spin-readout noise σ_R [13, 15]. Besides initialization into NV^- , the initial 2 μ s, 532 nm pulse (continuous-wave power $\approx 400 \mu$ W) also prepares the spin state into $m_s = 0$, that subsequently can be transferred to $m_s = -1$ with a π pulse. The following short 594 nm pulse (continuous-wave power ≈ 4.4 mW) then likely shelves the NV^- center into the singlet state when in $m_s = -1$ or leaves the population in the triplet state with a higher probability when in $m_s = 0$. Applied immediately after the shelving pulse, the triplet state of the NV center is ionized with a 29 mW (maximum available), 594 nm pulse of duration t_{ion} , thus effectively mapping the NV center spin states onto the distribution of charge states. Finally, the charge state is read out using a weak 15 ms long (continuous-wave power 3.5 μ W) 594 nm pulse. The optimal duration and power of each pulse has been determined separately [30]. As an example, in Fig. 3(b) we plot the integrated photon counts α_{m_s} acquired during the first 2 ms readout window for the initial spin states $m_s = 0$ and $m_s = -1$ as a function of the ionization-pulse duration t_{ion} . The SCC readout contrast $C = 1 - \alpha_0/\alpha_{-1}$ is plotted in Fig. 3(c). The maximum contrast $C_{max} \approx 32\%$ is found with an optimal $t_{ion} \approx 50$ ns and similar to the maximum contrast value achieved in the standard photoluminescence-based (PL) readout [30]. With further increasing t_{ion} , the spin contrast decreases due to the relaxation of the singlet-state population back to the ground state and vanishes at $t_{ion} \approx 300$ ns, the approximate singlet-state lifetime. The spin-readout contrast with the glycerol-coated surface is similar to the value obtained with the pristine surface condition.

The m_s -dependent photon-number distributions for NV_A are plotted in Fig. 3(d) and (e) for the pristine (d) and the glycerol-coated (e) surface, from which we extracted the respective NV^- population \tilde{p}_{m_s} [10, 13]. While for the pristine surface, the difference $\tilde{p}_{-1} - \tilde{p}_0 \approx 0.145$, the value increases to ≈ 0.19 after adding glycerol, that is a direct result of the charge-state stability improved with glycerol. However, in the SCC-based spin readout, the final charge state is determined by counting photons and assigning the charge/spin states based on a threshold photon number n_{th} [15]. The precision of assigning the correct charge and thus spin state depends on the distinguishability of the photon number distributions $P_{m_s}(n)$ for the initial spin states m_s . In order to

quantify the improved distinguishability of $P_{m_s}(n)$ after coating the surface with glycerol, we performed a Kolmogorov-Smirnov test that measures the maximum difference between the m_s dependent cumulative photon distributions. The test yields values of 0.145 for the pristine surface and 0.174 for the glycerol-coated surface, an improvement of $\approx 20\%$. We note that no post-selection of the data was applied to discard for example events executed in the NV^0 state [18].

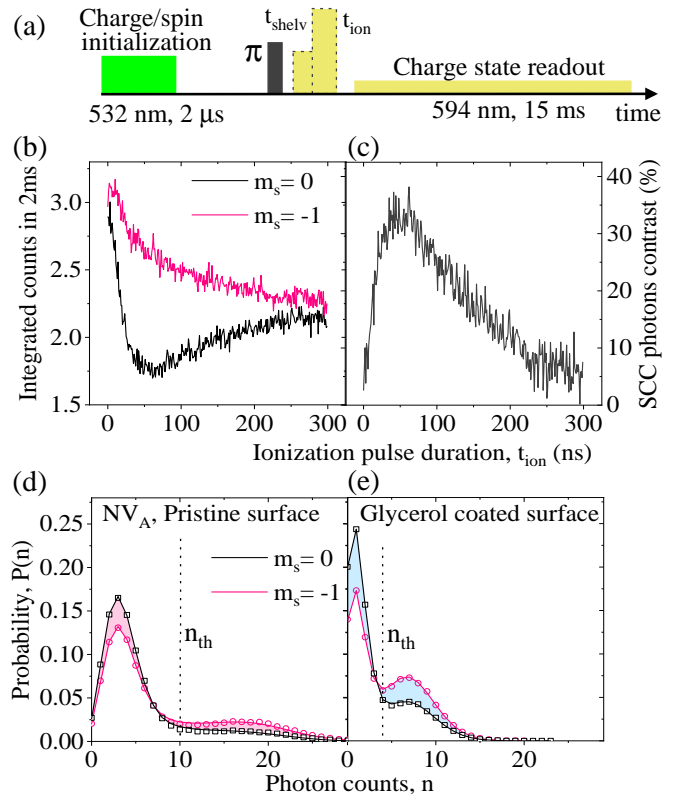


FIG. 3. SCC protocol and effects of surface condition. (a) Illustration of the pulse sequence to implement the SCC protocol, where the height of the orange (594 nm) pulses indicates the strength. (b) Photon counts integrated in 2 ms of the readout pulse for initial $m_s = 0$ and $m_s = -1$ spin states, respectively, and (c) contrast as a function of ionization-pulse duration t_{ion} . (d, e) The photon number distributions $P(n)$ of NV_A for the initial spin states $m_s = 0$ and $m_s = -1$ with the pristine (d) and the glycerol coated surface (e). The optimal threshold photon number n_{th} for the distributions is indicated.

For a set n_{th} the spin-readout noise can be calculated via [13]

$$\sigma_R^{SCC}(t_R) = \sqrt{(p_0 + p_{-1})(2 - p_0 - p_{-1}) / (p_0 - p_{-1})^2}, \quad (1)$$

where p_0 and p_{-1} are the probabilities for the initial spin states $m_s = 0$ and $m_s = -1$ to measure NV^- at time t_R during the readout step, respectively. Extracted from the distributions $P_{m_s}(n)$, in Fig. 4(a) we plot $\sigma_R^{SCC}(t_R)$ for NV_A both for the pristine and the glycerol-coated sur-

face. With increasing t_R , more photons are accumulated and the confidence for assigning the correct spin state improves. Hence, $\sigma_R^{\text{SCC}}(t_R)$ decreases to an optimal value. For longer t_R , charge-state switching occurs, thus causing uncertainty in determining the correct spin state and increasing $\sigma_R^{\text{SCC}}(t_R)$. With the glycerol-covered surface, $\sigma_R^{\text{SCC}}(t_R)$ is higher initially due to generally lower photon counts and the optimal $\sigma_R^{\text{SCC}}(t_R)$ is obtained at later times as a result of the improved charge-state stability.

Fig. 4(b) illustrates the optimal $\sigma_R^{\text{SCC}}(t_R)$ versus the charge initialization probability for NV_A – NV_D . It is evident that the readout noise improves with increasing $P_0(\text{NV}^-)$, respectively decreasing Γ^{-0} (see Fig. 2(a)) irrespective of the surface. The readout noise is higher for the charge-unstable NV centers (e.g. NV_A and NV_B) and the improvement upon application of glycerol is significant. The influence of glycerol on σ_R^{SCC} is minimal for the NV centers that are charge stable already with the pristine surface (e.g. NV_C and NV_D). All key parameters for NV_A – NV_D are summarized in Table. I, both for the pristine (P) and the glycerol-covered (G) surface. In the experiments, the maximum readout duration t_R was 15 ms. However, the significantly reduced Γ^{-0} af-

ter adding glycerol enables extended measurement times $t_R > 15$ ms. We thus simulated the measurement process [30] to extract the optimal t_R and n_{th} that minimizes σ_R^{SCC} globally. It is clear, that for all four NV centers glycerol allows for extended measurement times compared to the pristine surface. The minimum readout noise we obtain is $\approx 5\sigma_p$ for NV_D with $P_0(\text{NV}^-) \approx 0.75$. This result is comparable to the readout noise previously obtained with a shallow NV center in a nanopillar [24] with significantly higher photon counts. We note that with the diamond sample turned over and the NV centers adjacent to the immersion oil with higher photon counts, we obtain a readout noise as low as $\approx 3.5\sigma_p$.

DISCUSSION

Deuterated glycerol not only increases the spin coherence of near-surface NV centers as shown previously [32], but it generally improves the initialization probability $P_0(\text{NV}^-)$ into the negative charge state and reduces the ionization rate Γ^{-0} from NV^- to NV^0 . Our sample preparation routine with tri-acid cleaning only yields a partial surface termination with oxygen. Hence, the general improvement of the NV charge properties with glycerol could be assigned to the passivation of surface-related charges and traps [9, 10]. It is, however, also possible that glycerol lowers the Fermi level outside the diamond, reducing the effect of energy-band bending and thus improving the charge stability of NV^- [23, 33]. Irrespective of the physical mechanism, our findings highlight the influence of the surface-related charge environment on $P_0(\text{NV}^-)$ as well as Γ^{-0} during the readout with a weak selective 594 nm laser.

In the following, we discuss the benefit of SCC compared to the standard PL readout in the context of a realistic sensing sequence. The flat sample geometry, although practical, in our case limits the photon counts to approx. 65 kHz with 532 nm excitation at saturation. With PL spin readout in a 1 μs window, we thus obtain $\sigma_R^{\text{PL}} \approx 30\sigma_p$ [30], a factor 6 higher than the lowest $\sigma_R^{\text{SCC}} \approx 5.2\sigma_p$ we obtained for NV_D . Our results demonstrate that even with a pristine surface, it is feasible to locate charge-stable NV centers, implanted ≈ 5 nm deep, for which $\sigma_{R,min}^{\text{SCC}}$ is comparable to values previously only obtained from NV centers in nanobeams or deep inside bulk diamonds. However, the flat sample geometry as applied here and although practical, limits the attainable photon count rate. To minimize σ_R^{SCC} , the t_R is thus required to be of the order of several ms to collect a sufficient number of photons. These optimal times are even longer with the glycerol-coated surface as the photon collection efficiency is reduced. To account for the variability in the measurement overhead, we estimate the sensitivity to magnetic fields $\eta \propto \sigma_R(t_R) \sqrt{(\tau + t_I + t_R)/\tau^2}$ [13], where τ , t_I , and t_R are the interrogation, the ini-

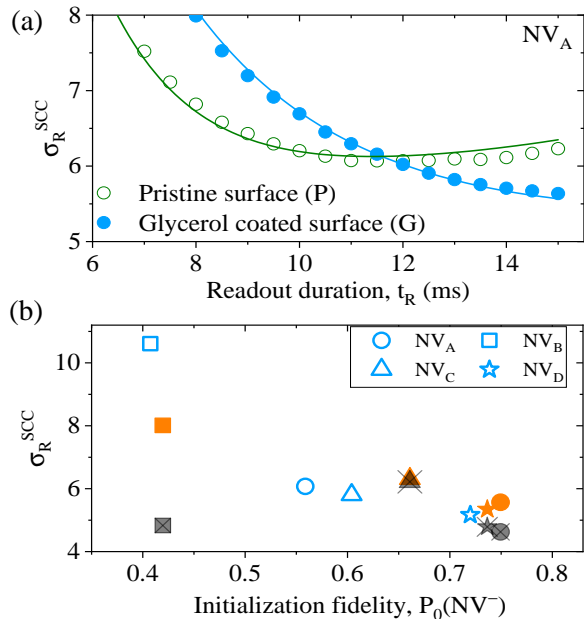


FIG. 4. Charge-initialization probability and spin-readout noise. (a) Measured spin-readout noise, σ_R^{SCC} for NV_A versus readout duration t_R . The symbols are calculated from the measured distributions [cf. Fig. 3(d) and (e)] and the solid lines are calculated from the extracted rates. (b) Optimal σ_R^{SCC} versus charge-initialization probability $P_0(\text{NV}^-)$ for NV_A – NV_D . The open and solid symbols represent measured values with the pristine and the glycerol-coated surface, respectively. The crossed symbols show the calculated optimal values for the case of the glycerol-coated surface. The impact of glycerol coating on σ_R^{SCC} is substantial for the charge-unstable NV center, NV_B .

	P ₀ (NV ⁻)		Γ ⁻⁰ (H _z)		σ _R ^{SCC} (σ _p) (measured)		σ _R ^{SCC} (σ _p) (simulated)		n _{th} (measured)		n _{th} (simulated)		t _R (ms) (measured)		t _R (ms) (simulated)	
	P	G	P	G	P	G	P	G	P	G	P	G	P	G	P	G
NV _A	0.56	0.75	101.3	8.5	6.0	5.6	6.1	4.6	7	4	6	11	10.4	14.9	8.7	55.9
NV _B	0.42	0.52	157.3	103.5	10.7	8.2	10.6	4.8	3	3	3	16	4.3	14.9	3.8	138
NV _C	0.60	0.66	73.83	15.7	5.8	6.1	5.8	6.2	7	5	8	6	10.9	15	12.6	21.3
NV _D	0.72	0.74	22.5	8.4	5.2	5.4	5.2	4.8	8	4	7	9	12.8	15	11.2	49.4

TABLE I. Summary of the key parameters measured and simulated for NV_A – NV_D for the pristine (P) and the glycerol-coated (G) surface condition. The uncertainty in σ_R is around 0.1σ_p.

tialization and the readout times, respectively. Considering a similar initialization-pulse duration of 1 μs, and an optimal readout duration for PL (1 μs) and SCC (12 ms for NV_A) minimizing σ_R, we obtain η_{SCC} < η_{PL} for τ > 500 μs. For relaxometry measurements that are conducted on time scales T₁ ≈ 1 ms, SCC thus has an advantage compared to PL readout. The interrogation times τ > 500 μs required for SCC to be beneficial are much longer than the T₂ coherence times (3 to 15 μs) measured for the shallow NV centers in our sample. The T₂ times can however further be increased to a benefit of SCC by applying higher-order dynamical-decoupling sequences [34], by coherently driving bath spins in the NV environment [35, 36], or via application of a concatenated driving scheme [37, 38]. We thus anticipate that for the implementation of T₁-relaxometry and dynamical decoupling [18] sensing schemes on shallow NV centres, it is advantageous to use the SCC instead of the PL readout. The minimum interrogation time beyond which SCC is beneficial can be further decreased via application of suitable photonic structures [7, 8] increasing the photon count rate.

CONCLUSION AND OUTLOOK

In summary, in this article we investigated the charge-state stability of single NV centers implanted with a mean depth ≈ 5 nm below the surface of a flat diamond sample. Applying standard processing and surface preparation by means of tri-acid cleaning [26], we observe a strong variation in the probability for initializing the NV centers into the negative charge state. The NV⁻ charge-state initialization probability increases for all investigated NV centers after coating the diamond surface with glycerol, and reaches up to ≈ 75% that is comparable to NV centers deep in the bulk. Our observations thus demonstrate that deuterated glycerol does not only enhance the coherence time of near-surface NV centers [32], but also improves the initialization probability and stability of the negative-charge state NV⁻. While the role of surface electron traps on charge-state stability [9, 10, 39] and their detrimental effects on spin-

based measurement protocols are recognized [10, 40], the exact physical mechanism of our observations is not entirely clear. We hypothesize the observations may also be explained by a reduction of the effect of energy-band bending via a change of the local electric-field potential. Further investigations are thus required, including surface electron spectroscopy [41], electrical manipulation via application of a gate voltage [42], and variation of different oxygen and hydrogen surface terminations [23].

We demonstrate the SCC protocol for shallow NV centers, obtaining a minimum readout-noise figure σ_R^{SCC} in the range 5 to 6σ_p, a substantial reduction compared to standard PL readout with σ_R^{PL} ≈ 35σ_p. Previously, SCC has only been achieved with NV centers located far from the diamond surface where surface-related charge instabilities are insignificant or in nano-beams with higher photon collection efficiency. For NV centers where glycerol significantly lowers the ionization rate, thus improving charge stability during readout, we observe an improvement of σ_R^{SCC} as prolonged readout times are allowed. However, the low photon count rate, limited by our sample configuration, requires extended readout times with the optimum t_R > 4 ms. With our current configuration, an improvement in terms of sensitivity is thus achieved for measurement sequences with an interrogation time τ > 500 μs, comprising relaxometry, dynamical decoupling and concatenated driving schemes. We expect that the optimal readout times can substantially be lowered by increasing the photon collection efficiency, reducing t_R and yielding a benefit of SCC for interrogation times << 500 μs.

Our findings will pave the way towards the application of the SCC protocol for near-surface NV centers with significantly improved noise figures compared to standard PL readout. Structuring the diamond with for example nano-pillars will enhance the photon collection efficiency, thus improving the sensitivity even further for shorter interrogation times.

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